NSN 5961-01-290-1919

Diode Semiconductor Device - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-290-1919 **Inclosure Material:** Metal **Overall Length:** 5.710 inches **Function For Which Designed:** Rectifier **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case and quality assurance level tx **Overall Width Across Flats:** 1.063 inches **Thread Size:** 0.375 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 240.0 nonrepetitive peak reverse voltage and 200.0 working peak reverse voltage **Current Rating Per Characteristic:** 75.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Test Data Document:** 81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud **Specification Data:** 81349-mil-prf-19500/246 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**

A110a0

No Fiig:

NSN 5961-01-290-1919

Diode Semiconductor Device - Page 2 of 2



Mil-std (military Standard):

Mil-prf-19500 spec.